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Piezoelectricity, a phenomenon known for centuries, is an effect that is about the production of electrical potential in a substance as the pressure on it changes. Wurtzite structures such as ZnO, GaN, InN and ZnS, due to the polarization of ions in a crystal that has non-central symmetry, a piezoelectric potential (*piezopotential*) is created in the crystal by applying a stress. The effect of piezopotential to the transport behavior of charge carriers is significant due to their multiple functionalities of piezoelectricity, semiconductor and photon excitation. By utilizing the advantages offered by these properties, a few new fields have been created. Electronics fabricated by using inner-crystal piezopotential as a "gate" voltage to tune/control the charge transport behavior is named *piezotronics*, with applications in strain/force/pressure triggered/controlled electronic devices, sensors and logic units. *Piezo-phototronic effect* is a result of three-way coupling among piezoelectricity, photonic excitation and semiconductor transport, which allows tuning and controlling of electro-optical processes by strain induced piezopotential. The objective of this talk is to introduce the fundamentals of piezotronics and piezo-phototronics and to give an updated progress about their applications in energy science (LED, solar) and sensors (photon detector and human-CMOS interfacing).

## References

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